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View online: http://dx.doi.org/10.1063/1.4945740
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Power-dependent spin amplification in (In, Ga)As/GaAs quantum well via Pauli blocking by tunnel-coupled quantum dot ensembles

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(Received 17 January 2016; accepted 29 March 2016; published online 11 April 2016)

Power-dependent time-resolved optical spin orientation measurements were performed on In0.1Ga0.9As quantum well (QW) and In0.5Ga0.5As quantum dot (QD) tunnel-coupled structures with an 8-nm-thick GaAs barrier. A fast transient increase of electron spin polarization was observed at the QW ground state after circular-polarized pulse excitation. The temporal maximum of polarization increased with increasing pumping fluence owing to enhanced spin blocking in the QDs, yielding a highest amplification of 174% with respect to the initial spin polarization. Further elevation of the laser power gradually quenched the polarization dynamics, which was induced by saturated spin filling of both the QDs and the QW phase spaces. © 2016 AIP Publishing LLC.

Quantum-coupled nanostructures have been the subject of intense research owing to the fact that composite nanosystems possess the properties of each component, which renders them an ideal platform for exploring the physics and materials functions. One example is quantum well (QW) and quantum dot (QD) tunnel-coupled nanostructures. In such hybrid systems, QWs serve as reservoirs for carriers/excitons, whereas the three-dimensional (3D) potential surrounding QDs efficiently confines the carrier/exciton motion. This confinement leads to long-lived spin states due to the suppression of spin–orbit interaction-induced relaxation processes. Therefore, QDs have been demonstrated to be efficient spin filters. Enhanced electron spin polarization was observed at excited states (ESs) of QDs by spin blocking from ground states (GSs). Although extensively studied, these previous works mainly focused on the localized spin states of the QDs. Wider application of this spin amplification effect can be found by tunnel-coupling QDs with quasi-two-dimensional (2D) mobile carriers/excitons in QWs. There are two major advantages of such hybrid structures: (i) the tunneling process is spin-conserving, and (ii) the coupling strength can be controlled by the barrier thickness and height, enabling additional quantum engineering that cannot be achieved with QWs or QDs alone. By integrating current mature QW-based opto-electronic devices with the spin-filter function of QDs, quantum-coupled nanostructures can be fabricated for use in spin-polarized light-emitting/laser diodes (LED/LDs). Therefore, by employing time-resolved optical spin orientation spectroscopy in this work, we focused on the excitation power-dependent spin amplification effect in a (In, Ga)As/GaAs QW tunnel-coupled with spin-polarized QD ensembles.

The (In, Ga)As/GaAs QW–QD coupled structure was grown by molecular beam epitaxy (MBE) on a [001]-oriented GaAs substrate with a 400-nm-thick GaAs buffer layer. Separated by an 8-nm-thick GaAs tunneling barrier, the In0.1Ga0.9As QW has a thickness of 20 nm, whereas the In0.5Ga0.5As QD ensembles have an average basal diameter and height of 20 nm and 5 nm, respectively. An areal dot density, nD, of ~2 × 1012 cm−2 was revealed by scanning electron microscopy (SEM). Finally, the QD layer was capped with a 50-nm-thick GaAs layer. It should be noted that the sample is slightly p-type doped due to residual carbon acceptors in the GaAs layer. Schematically shown in the inset of Figure 1(a) is the high-angle angular dark-field (HAADF) scanning transmission electron microscopy (STEM) image of the coupled structure, where the QDs and QW are outlined by dashed lines. The arrow bar denotes a scale of 20 nm.

The time-resolved optical spin orientation study was performed at 6 K in a He-cycling cryostat. A mode-locked Ti:sapphire pulsed laser with a repetition rate of 76 MHz and a temporal width of 150 fs was used as the excitation source. To resonantly generate spin-polarized carriers inside the QW, a linear polarizer and a quarter-wave plate were employed at the excitation side, and the laser photon energy was tuned to 1.46 eV, which is below the GaAs bandgap of approximately 1.52 eV at 6 K. Because the QW GS wavefunction is tunnel-coupled with QDs through the thin barrier layer, the photo-excited carriers in the QW could be transferred to the dots with no loss of spin and subsequently relax to the localized QD ES. Time-resolved PL emissions from the QW and QDs were detected by a streak camera system combined with a single grating monochromator. To distinguish the circular-polarized (σ+ and σ−) emission from the coupled structure, we applied another linear polarizer and quarter-wave plate on the detection side.

Figure 1(a) shows the 6 K circular polarization-resolved photoluminescence (PL) spectra measured at a pumping density, Pexc, of 7.1 W/cm². The entire PL emission is strongly co-polarized with laser helicity (σ−). A relatively sharp PL transition centered at 1.413 eV arises from the QW GS at the
Brillouin center \((k = 0)\). Below this transition is a much broader emission from 1.30 to 1.39 eV, mainly coming from the ES emission of the QDs. Because of the response limit of the streak camera detector, the PL intensity decreases considerably toward the low energy side. By using another CCD detector from SpectrumOne with low excitation power, the GS of the QD ensembles was observed at 1.280 eV after spectral deconvolution, as shown by the dotted line in Figure 1(c). Calculation of the QD energy levels based on Ref. 20 gave two excited states, ES1 and ES2, positioned at 1.331 eV and 1.383 eV, respectively. Because the energy separation between QD ES2 and QW GS was only \(\sim 30\) meV, which is smaller than the QD inter-level spacing of \(\sim 50\) meV, the carriers excited in the QW were injected into the QDs mainly via the non-resonant tunneling process. By calculating the PL circular polarization degree (CPD), i.e., \(\text{CPD} = (I_{\sigma^+} - I_{\sigma^-})/(I_{\sigma^+} + I_{\sigma^-})\), where \(I_{\sigma^+}\) and \(I_{\sigma^-}\) are the \(\sigma^+\) and \(\sigma^-\) polarized PL intensities, the QW GS gave a CPD value of approximately 50%. For the QD emission, its polarization decreases steadily from ES2 toward the low energy side and reaches almost zero at GS, indicating a full occupation of spin states. This feature is characteristic of the spin-dependent intra-level carrier relaxation, i.e., the spin blockade effect. Since holes in QWs experience stronger spin–orbit interaction and mixing of heavy-light hole sub-valence bands, their spins are easily randomized, which leaves electron spins better preserved to determine the PL helicity of the QW and QDs. By increasing \(P_{\text{exc}}\) to 14.2 W/cm\(^2\)—see Figure 1(b), the CPD of the QW and QD ES2 increased to \(\sim 60\)% . At the same time, the QD emission was blue-shifted, caused by enhanced state filling under higher pumping. However, further increasing the laser power drastically reduced the CPD of the QDs and QW to almost zero at the highest \(P_{\text{exc}}\) of 27.1 W/cm\(^2\)—see, e.g., Figure 1(c). The QD emission then merged with the QW GS transition, resulting in the appearance of an extended “hot-carrier” PL tail over the QW GS continuum \((|k| > 0)\) at the higher energy side, which is a clear sign of saturation in both the QDs and the QW. The observed power dependence of circular polarization, together with the concurrent change of the PL spectral shape, points to their close correlation.

To gain insight into the underlying spin dynamics, we turned to time-resolved PL. Shown in Figure 2(a) are the \(\sigma^+\)- and \(\sigma^-\)-polarized PL transients from the QW GS at \(P_{\text{exc}}\) of 7.1 W/cm\(^2\). Both PL traces feature fast decay of approximately 24 ps, which was induced by rapid tunnel-injection of carriers from the QW GS to the QD ES, as reported before. For comparison, Figure 2(a) also includes the unpolarized PL decay (stars) from a reference QW fabricated using the same growth conditions. The reference QW shows typical radiative decay around 1 ns. The time evolution of CPD based on circular PL dynamics is displayed in Figure 2(d) as triangles. An initial CPD, \(\text{CPD}_{\text{init}}\), of 43% is observed at the

FIG. 1. 6 K circular-polarized PL spectra measured at the excitation density, \(P_{\text{exc}}\), of (a) 7.1 W/cm\(^2\), (b) 14.2 W/cm\(^2\), and (c) 27.1 W/cm\(^2\). The corresponding CPD is given as dashed curve. Scheme for optical excitation and subsequent spin-dependent tunneling of QW GS electrons, together with HAADF-STEM image of QW-QD coupled structure, is given in (a). The arrow bar denotes 20 nm length scale. QD GS PL spectrum is shown as dotted line in (c).

FIG. 2. (a)–(c) 6 K Circular-polarized time-resolved PL of QW GS as a function of \(P_{\text{exc}}\). For comparison, unpolarized PL decay of a reference QW was shown as stars in (a). (d) The derived transient CPD from circular-polarized PL at \(P_{\text{exc}}\) of 7.1 W/cm\(^2\) (triangles), 14.2 W/cm\(^2\) (dots), and 27.1 W/cm\(^2\) (stars), the lines are guide to the eye.
time origin, reflecting electron spin polarization generated by laser excitation in the QW. In such a case, the \( \sigma^- \)-polarized laser at 1.46 eV is in resonance with the heavy/light hole–electron transition with a 3:1 absorption intensity ratio according to the selection rule.\(^{10,24}\) This leads to a 50% electron spin polarization in the QW, which is quite close to the \( CPD_{t=0} \) value we observed. The discrepancy between theoretical and measured values is most likely caused by the loss of a small fraction of electron spins during energy relaxation to the QW GS. It is noteworthy that, after laser pulse, there is a fast increase of \( CPD \) up to a maximum value, \( CPD_{\text{max}} \), of 62% within \( \sim 100 \) ps, yielding an amplification factor, \( CPD_{\text{max}}/CPD_{t=0} \), of 144%. The transient increase of \( CPD \) can be explained by spin-dependent tunneling of electrons from the QW to the QDs, as illustrated in the inset of Figure 1(a), i.e., the majority spin-down electrons generated by the \( \sigma^- \) laser quickly occupied the corresponding spin sub-levels in the QDs after excitation, which hindered further spin injection from the QW GS via the Pauli blocking effect. However, spin-up minorities can feed into the QDs without bafflement. The combined effects of the two spin polarizations thus lead to an initial increase of \( CPD \) at the QW GS. It can be inferred that a stronger spin-polarized state filling in QD ensembles would favor spin amplification at the QW GS. Indeed, at an elevated \( P_{\text{exc}} \) of 14.2 W/cm\(^2\)—see Figure 2(b), the increased occupation of spin levels in the QDs suppressed carrier injection from the QW, resulting in longer PL decay for both \( \sigma^- \) and \( \sigma^+ \) components. Meanwhile, the relatively weaker blocking of the minority spin-up electrons led to faster \( \sigma^- \) PL decay than that for \( \sigma^+ \) polarization. The resulting time-dependent \( CPD \) is shown in Figure 2(d) as dots. We can see that \( CPD_{\text{max}} \) increased up to 75%. Given the same \( CPD_{t=0} \) of 43%, a maximal transient amplification of 174% was obtained. After reaching its temporal peak, \( CPD \) decayed due to electron spin relaxation at the QW and QD states. For the QW, spin-flip at the QW GS directly decreased \( CPD \), whereas for the QDs, it weakened the Pauli blocking of the spin-down majority electrons and rebalanced the spin populations in the QW. To compare their relative contributions to the \( CPD \) dynamics, we measured the spin relaxation times of QD ES/QW GS, \( \tau_{\text{QD/QW}}^s/\tau_{\text{QD/QW}}^r \), within the spectral range of 1.34–1.39 eV/1.41–1.42 eV from coupled structure/reference single QW. The results are displayed in Figure 3(a) as squares and stars for QD ES and QW GS, respectively. The value of \( \tau_{\text{QD}}^s \) \( \sim 0.32 \) ns, is found much faster than \( \tau_{\text{QW}}^s \), \( \sim 0.8 \) ns, implying its dominant role in \( CPD \) decay at the QW GS. Actually, the PL circular polarization decreased monotonically with a characteristic time of \( \sim 0.30 \) ns, which is in good agreement with \( \tau_{\text{QD}}^s \). It should be noted that when both spin sub-spaces in the QDs become occupied, the \( CPD \) decay of the QW GS will become longer, and it will be mainly governed by \( \tau_{\text{QW}}^s \). The transient increase of \( CPD \) is closely dependent upon spin polarization in the QDs. This amplification effect diminishes both the spin-down and spin-up states in the QW GS and QDs are gradually saturated—see, e.g., Figure 2(c). At \( P_{\text{exc}} \) of 27.1 W/cm\(^2\), the \( \sigma^- \) and \( \sigma^+ \) PL transients from the QW GS \((k=0)\) overlay each other and exhibit a saturated decaying profile, which is evidence of phase space filling and is consistent with the “hot-carrier” tail of the QW GS shown in Figure 1(c). As a result, \( CPD_{t=0} \) is markedly reduced to \( \sim 6\)%, shown as stars in Figure 2(d), without an increase in polarization, i.e., \( CPD_{t=0} = CPD_{\text{max}} \).

Detailed power-dependent measurements were performed to obtain the relationship between optical pumping and polarization amplification. Shown in Figure 3(b) is the QW/QD PL ratio as a function of \( P_{\text{exc}} \). A threshold is found at approximately 15 W/cm\(^2\), which separates the power profile into unsaturated and saturated regimes. This transition of carrier occupation is corroborated by two factors. The first factor is the spectral change of the PL tail at the QW GS, as logarithmically plotted in the inset of Figure 3(b) for unpolarized detection. All spectra are normalized and displayed at energies relative to their peak at \( k=0 \). The corresponding excitation power is indicated by the same symbol in Figure 3(b). As can be seen, the PL tail at 7.1 W/cm\(^2\) (dots) and 14.2 W/cm\(^2\) (triangles) remains almost the same. It begins to increase when \( P_{\text{exc}} \) is increased to 17.8 W/cm\(^2\) (squares) and finally gets populated with “hot” carriers at 27.1 W/cm\(^2\) (stars). The second factor is the consistent \( P_{\text{exc}} \) dependence of \( CPD_{t=0} \), as shown in Figure 4(a), i.e., the initial polarization decreases as \( P_{\text{exc}} \) exceeds 15 W/cm\(^2\). Having identified the state of carrier filling in the coupled structure, we now summarize its effect on the amplification of spin polarization. In the unsaturated regime, \( P_{\text{exc}} < 15 \) W/cm\(^2\), stronger optical pumping intensifies the spin blocking of the QDs, giving rise to a larger polarization value, \( CPD_{\text{QD}} \), as shown in Figure 4(b). Driven by the enhanced blockade, both
The authors acknowledge the financial support from the Japan Society for the Promotion of Science (JSPS) by Grant-in-Aid for Scientific Research (S) No. 22221007, as well as the bilateral program promoted by JSPS.

FIG. 4. (a) \(P_{\text{exc}}\) dependence of initial, \(CPD_{l=0}\), temporal maximal, \(CPD_{\text{max}}\), and time-integrated, \(CPD_{\text{QW}}\), circular polarization of QW GS in coupled structure. (b) \(P_{\text{exc}}\) dependence of time-integrated circular polarization, \(CPD_{\text{QD}}\), of entire QD emission, together with the polarization amplification factor \(CPD_{\text{max}}/CPD_{l=0}\).

transient \(CPD_{\text{max}}\), and time-integrated polarization, \(CPD_{\text{QW}}\), of the QW GS increase with increasing \(P_{\text{exc}}\), reaching a peak at approximately \(P_{\text{exc}} = 14.2 \text{ W/cm}^2\). Beyond the \(P_{\text{exc}}\) threshold of 15 W/cm\(^2\), the \(CPD\) value of the QW GS decreases monotonically as spin saturation becomes increasingly important in the coupled structure. The amplification factor of the transient circular polarization, \(CPD_{\text{max}}/CPD_{l=0}\), is plotted against \(P_{\text{exc}}\) in Figure 4(b). It follows quite well the power dependence of \(CPD_{\text{QD}}\), manifesting the pivotal role of spin-dependent blockade in boosting the spin polarization in the QW.

In conclusion, time-resolved optical spin orientation spectroscopy was employed to study the spin amplification effect in (In, Ga)As/GaAs QW–QD tunnel-coupled nanostructures. Transient amplification of \(CPD\) at the QW GS was observed via Pauli blocking by spin-polarized QD ensembles, which can be tuned by laser power. The results presented in this work demonstrate the possibility of such zero-dimensional (0D)–2D hybrid quantum structures as optically controllable amplifiers for spin-based device applications.